L Number	Hits	Search Text	DB	Time stamp
1	436	(CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor)) with transistor with (light or radiation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 08:29
2	34	((CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor)) with transistor with (light or radiation)) and electromagnetic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 08:30
3	50891	(phototransistor or (photo$1transistor) or transistor) with (light or electromagnetic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 09:27
4	329	((CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor)) with transistor with (light or radiation)) and ((phototransistor or (photo$1transistor) or transistor) with (light or electromagnetic))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 09:00
5	303	(((CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor)) with transistor with (light or radiation)) and ((phototransistor or (photo$1transistor) or transistor) with (light or electromagnetic))) and (imaging or imager or image pickup or image device)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 10:49
6	16	((CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor)) with transistor with (light or radiation)) and ((phototransistor or (photo$1transistor)) with (light or electromagnetic))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 09:28
7	5	("5546438" | "5942774" | "6023081" | "6040592" | "6133862" | "2002/0093034" | "2002/0163042").PN.	USPAT	2004/08/23 09:40
8	271	348/273.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 10:24
9	31	(((CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor)) with transistor with (light or radiation)) and ((phototransistor or (photo$1transistor) or transistor) with (light or electromagnetic))) and (imaging or imager or image pickup or image device)) and (color adj1 filter)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 10:49
10	95	(transistor with (substrate near8 insulat$3) with light) and (CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor) adj4 (imager or imaging or sensor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 10:59
11	13	(transistor with (substrate near8 transparent) with light) and 250/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 11:11
-	936	((phototransistor or (photo$1transistor)) with light) same bias$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 08:58
-	18	(((phototransistor or (photo$1transistor)) with light) same bias$3) and 348/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 11:03
-	213	(((phototransistor or (photo$1transistor)) with light) same bias$3) and 250/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 11:08

-	3370	(transistor with light) same bias$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 11:25
-	123	((transistor with light) same bias$3) and 348/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 10:55
-	23	(((transistor with light) same bias$3) and 348/$.ccls.) and CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 11:02
-	29621	(substrate near8 transparent) with light	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 11:03
-	580	transistor with (substrate near8 transparent) with light	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 14:05
-	9	(transistor with (substrate near8 transparent) with light) and 348/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 11:03
-	13	(transistor with (substrate near8 transparent) with light) and 250/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 11:11
-	38	(transistor with light) same bias$3 same CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 13:00
-	49	(n adj1 (channel or type)) with (CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor)) with transistor with (light or radiation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/22 19:23
-	6	(n adj1 (channel or type)) with (CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor)) with transistor with sensitive with (light or electrogmanetic or radiation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 13:47
-	0	(transistor with (substrate near8 transparent) with light) same (CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 14:07
-	39	(transistor with (substrate near8 transparent) with light) and (CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 15:14
-	39	(transistor with (substrate near8 transparent) with light) and (CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor) adj4 (imager or imaging or sensor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 15:33

-	92	(transistor with (substrate near8 insulat$3) with light) and (CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor) adj4 (imager or imaging or sensor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 10:58
-	15	(output near7 (differential adj1 amplifier)) same (CMOS near4 (imager imaging sensor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 16:03
-	126	grating with color with light with (detector or pixel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/29 16:04
-	84	transistor with bias$3 with electromagnetic	USPAT	2004/08/22 18:00
-	49	(n adj1 (channel or type)) with (CMOS or (complementary adj1 metal adj1 oxide adj1 semiconductor)) with transistor with (light or radiation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/23 08:29
-	3	("5283460" | "6252286" | "6313484").PN.	USPAT	2004/08/22 19:26